NSN 5961-01-201-5322

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Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-201-5322 **Inclosure Material:** Ceramic **Overall Length:** Between 0.194 inches and 0.206 inches **Overall Diameter:** Between 0.187 inches and 0.220 inches **End Application:** Aircraft model sh-60b **Mounting Method:** Terminal Features Provided: Burn in **Semiconductor Material:** Gallium arsenide Voltage Rating In Volts Per Characteristic: 35.0 collector to emitter voltage, dc and 7.0 emitter to collector voltage, dc and 2.0 reverse voltage, dc **Terminal Type And Quantity:** 4 insulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli